

# YJ Planar Schottky Barrier Diode Die Specification

100V 30A, 122mil, Schottky barrier diode die based on silicon planar process

Part No.: PSB122S100AS-290A

## Main Products Characteristics

- Average forward current:  $I_{F(AV)} = 30$  A
- Maximum operating junction temperature:  $T_{jmax} = 175$  °C